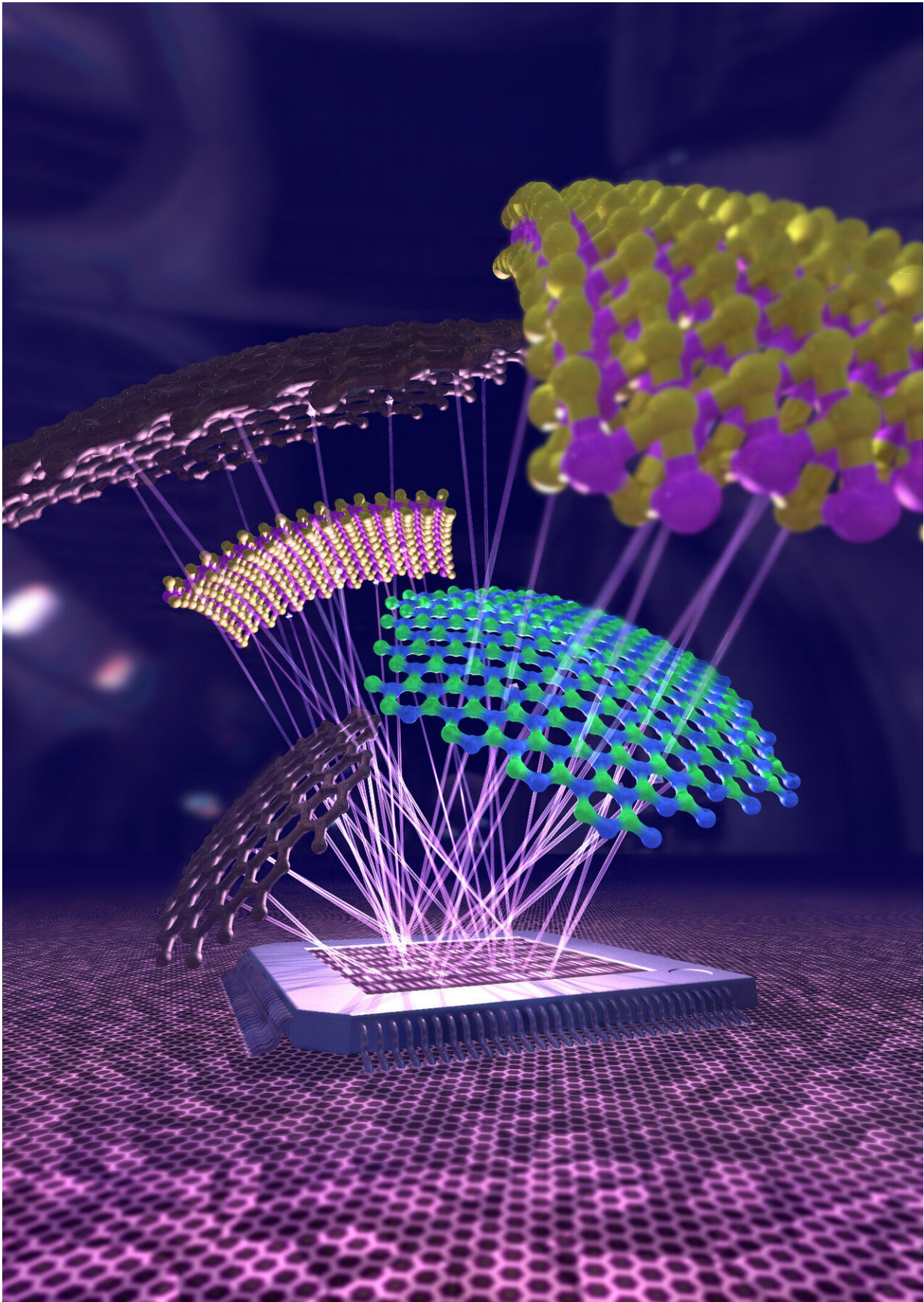


# **Silicon technology boost with graphene and 2-D materials**

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Artistic illustration of silicon technology combined with 2D materials. Credit: ICFO / F. Violla

Silicon semiconductor technology has done marvels for the advancement of our society, which has benefited tremendously from its versatile use and amazing capabilities. The development of electronics, automation, computers, digital cameras and recent smartphones based on this material and its underpinning technology has skyrocketed, downscaling the physical size of devices and wires to the nanometre regime.

Although this technology has been developing since the late 1960s, the miniaturization of circuits seems to have reached a possible end point, since transistors can only be shrunk down to a certain size and no further. Thus, there is a pressing need to complement Si CMOS technology with [new materials](#), and to fulfill the future computing requirements as well as the needs for diversification of applications.

Now, [graphene](#) and related two-dimensional (2-D) materials offer prospects for unprecedented advances in device performance at the atomic limit. Their amazing potential has proven to be a possible solution to overcome the limitations of silicon technology, where the combination of 2-D materials with silicon chips promises to surpass current technological limitations.

In a new review article in *Nature*, a team of international researchers including ICFO researchers Dr. Stijn Goossens and ICREA Prof at ICFO Frank Koppens, and industrial leaders from IMEC and TSMC have come together to provide an in-depth and thorough review on the opportunities, progress and challenges of integrating atomically thin

materials with Si-based technology. They provide insights on how and why 2-D materials (2DMs) may overcome current challenges posed by the existing technology and how they can enhance both device component function and performance, to boost the features of future technologies, in the areas of computational and non-computational applications.

For non-computational applications, they review the possible integration of these materials for future cameras, low power optical data communications and gas and bio-sensors. In particular, image sensors and photodetectors, are areas where graphene and 2DMs could enable a new vision in the infrared and terahertz range in addition to the visible range of the spectrum. These can serve, for example, in autonomous vehicles, security at airports and augmented reality.

For computational systems, and in particular in the field of transistors, they show how challenges such as doping, contact resistance and dielectrics/encapsulation can be diminished when integrating 2DMs with Si technology. 2DMs could also radically improve memory and data storage devices with novel switching mechanisms for meta;-insulator-metal structures, avoid sneak currents in memory arrays, or even push performance gains of copper wired based circuitry by adhering graphene to the ultrathin copper barrier materials and thus reduce resistance, scattering and self-heating.

The review provides insight to all stakeholders about the challenges and impact of solving the 2-D material integration with CMOS technology. It provides a roadmap of 2-D integration and CMOS technology, pinpointing the stage at which all challenges regarding growth, transfer, interface, doping, contacting, and design are currently standing today and what possible processes are expected to be resolved to achieve such goals of moving from a research laboratory environment to a pilot line for production of the first devices that combine both technologies.

The first 2-D material-CMOS roadmap, as presented in this review, gives an exciting glimpse in the future, with the first pilot production to be expected just a few years from now.

**More information:** Deji Akinwande et al. Graphene and two-dimensional materials for silicon technology, *Nature* (2019). [DOI: 10.1038/s41586-019-1573-9](https://doi.org/10.1038/s41586-019-1573-9)

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